## NSN 5962-00-530-4660

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 0.735 inches and 0.830 inches
Body Width:
Between 0.245 inches and 0.295 inches
Body Height:
Between 0.055 inches and 0.125 inches
Maximum Power Dissipation Rating:
700.0 milliwatts
Operating Tempurature Range:
-55.0/+85.0 degrees celsius
Storage Tempurature Range:
-62.0/+125.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and low power and 3-state output and positive outputs
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
11 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
20.0 volts power source
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
94117-310117 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format;
excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental
and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

**Fiig:** A458a0

Yes - demil/mli